

## SSCE5V021N7

Ultra Low Capacitance Array for ESD Protection

## Description

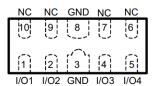
The SSCE5V021N7 is an ultra low capacitance TVS array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines.

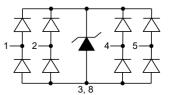
The SSCE5V021N7 has an ultra-low capacitance with a typical value at 0.3pF, and complies with the IEC 61000-4-2 (ESD) with ±25kV air and ±25kV contact discharge. It is assembled into a 10-pin 2.5x1.0x0.5mm lead-free DFN package. The flow through style package allows for easy PCB layout and matched trace lengths necessary to maintain consistent impedance between high speed differential lines such as USB 3.0 and HDMI. The small size, ultra-low capacitance and high ESD surge protection make SSCE5V021N7 an ideal choice to protect HDMI, MDDI, USB 3.0 and other high speed ports.

## Feature

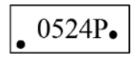
- $\Rightarrow$  70W peak pulse power (t<sub>P</sub> = 8/20µs)
- ♦ DFN2510-10L Package
- ♦ Working voltage: 5V
- ♦ Low clamping voltage
- ♦ Low capacitance
- RoHS compliant transient protection for high speed data
   lines to IEC61000-4-2(ESD)±25kV(air),±25kV(contact)

## PIN configuration





Top view



**Marking** 

#### Applications

- ♦ DVI & HDMI Port Protection
- Serial and Parallel Ports
- ♦ Projection TV
- Notebooks, Desktops, Server
- ♦ USB 1.1/2.0/3.0/3.1/OTG
- ♦ HDMI 1.3, HDMI 1.4

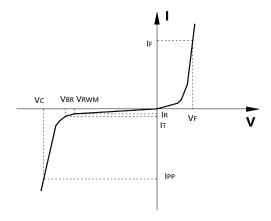
#### Mechanical data

- ♦ Lead finish:100% matte Sn(Tin)
- ♦ Mounting position: Any
- ♦ Qualified max reflow temperature:260°C
- ♦ Device meets MSL 3 requirements
- ♦ Pure tin plating: 7 ~ 17 um
- ♦ Pin flatness:≤3mil



## • Electronic Parameter

Symbol	Parameter	
V <sub>RWM</sub>	Peak Reverse Working Voltage	
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>	
V <sub>BR</sub>	Breakdown Voltage @ I⊤	
lτ	Test Current	
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
P <sub>PP</sub>	Peak Pulse Power	
CJ	Junction Capacitance	



# ● Absolute maximum rating @TA=25°C

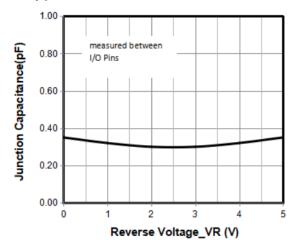
Parameter		Symbol	Value	Unit
Peak Pulse Power(8/20µs)		P <sub>PP</sub>	70	W
Peak Pulse Current (8/20µs)		IPP	5	Α
ESD Rating per IEC61000-4-2:	Contact	V	25	1/1/
	Air	V <sub>ESD</sub>	25	KV
Storage Temperature		T <sub>STG</sub>	-55/+150	$^{\circ}$
Operating Temperature		TJ	-55/+125	$^{\circ}$

## ● Electrical Characteristics @TA=25°C

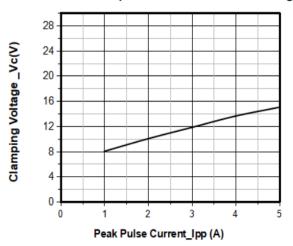
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Peak Reverse Working	V <sub>RWM</sub>	Any I/O to GND			5	V
Voltage						
Proakdown Voltago	\/	I⊤ = 1mA	6			V
Breakdown Voltage	$V_{BR}$	Any I/O to GND	O			
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =5.0V			1	μA
Diode Forward Voltage	VF	I <sub>F</sub> = 15mA		0.85	1.2	V
Clamping Voltage	Vc	I <sub>PP</sub> =1A, tP = 8/20μs		9.5		V
Clamping Voltage	Vc	I <sub>PP</sub> =5A, tP = 8/20μs			14	V
	<sup>2</sup> O	$V_R = 0V$ , $f = 1MHz$ ,		0.3	0.4	pF
Junatian Canasitanas		between I/O pins		0.3		
Junction Capacitance		VR = 0V, f = 1MHz,	0.6		0.0	
		any I/O pin to GND		0.6	0.8	pF



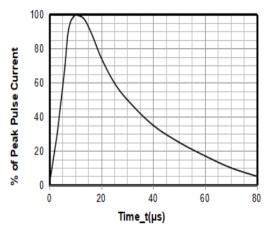
## Typical Performance Characteristics



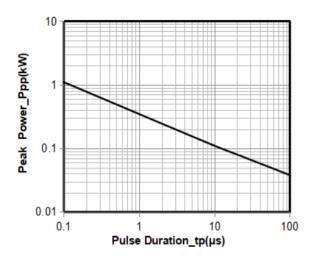
Junction Capacitance vs. Reverse Voltage



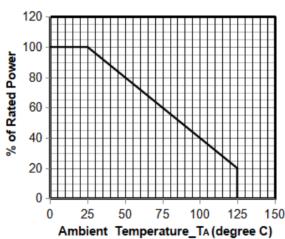
Clamping Voltage vs. Peak Pulse Current



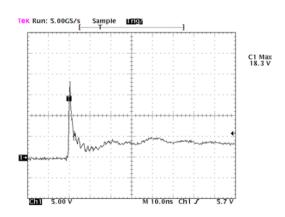
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



**Power Derating Curve** 



Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2



## • Package Information

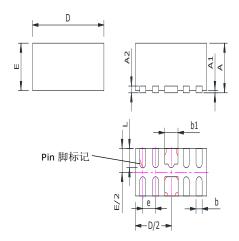
## **Ordering Information**

Device	Package	Qty per Reel	Reel Size
SSCE5V021N7	DFN2510-10L	3000	7 Inch

## **Mechanical Data**

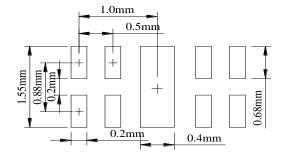
Case: DFN2510

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters			
	Min	Max		
Α	0.45	0.65		
<b>A</b> 1	0.05REF			
A2	0.15REF			
b	0.15	0.25		
b1	0.30	0.50		
D	2.424	2.576		
E	0.924	1.076		
е	0.50REF			
L	0.30	0.45		

## **Recommended Pad outline**





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